

N-Type GSD7S72T [565-595W]

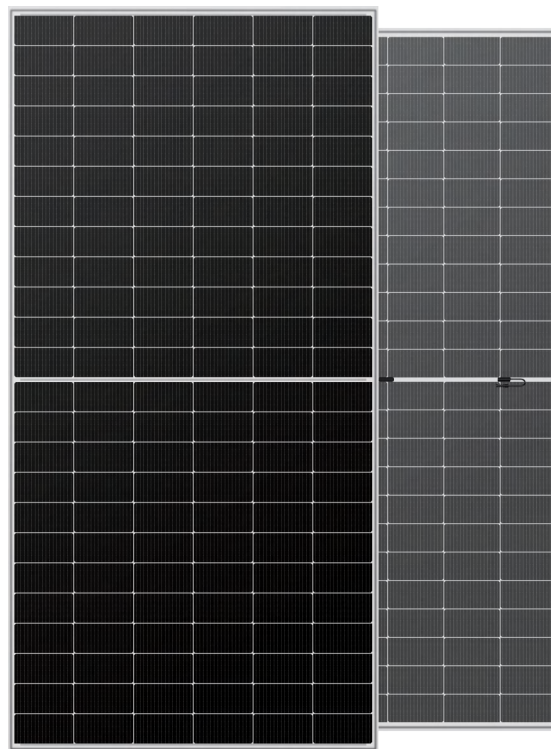
Bifacial Dual Glass 16BB Half-cut Mono Topcon

IEC 61215 / IEC 61730 / UL 61730

ISO9001:2015: Quality Management System

ISO14001:2015: Environment Management System

ISO45001:2018: Occupational Health And Safety Management System



KEY FEATURES



SMBB Technology

Better light trapping and current collection to improve module power output and reliability.



Lower Attenuation

Components have better reliability and lower LID/LETID attenuation



Double Power Output

For higher power output, backside power output can be increased 5-25%



Wider Application

No water-permeability and high wear-resistance, can be widely used in high-humid, windy and dusty area



PID Resistance

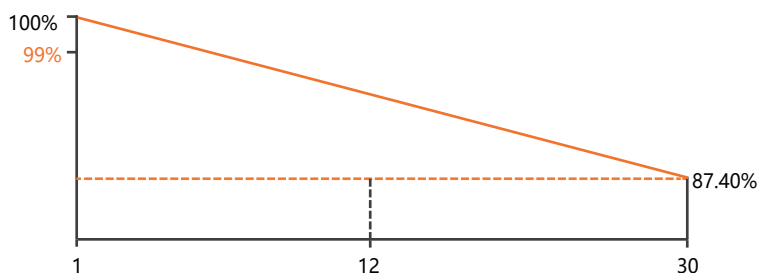
Excellent Anti-PID performance guarantee via optimized mass-production process and materials control

Guaranteed Power Performance

25 Years Product Warranty

30 Years Linear Power Warranty

0.40% Annual Degradation Over 30 Years



As different markets have different certification requirements, please consult our G-Star sales group to obtain the corresponding certification for the local market. If any special requirements are needed for the specific installing environment, please feel free to contact G-star technical support department anytime.

GSD7S72T

565-595W

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Weight

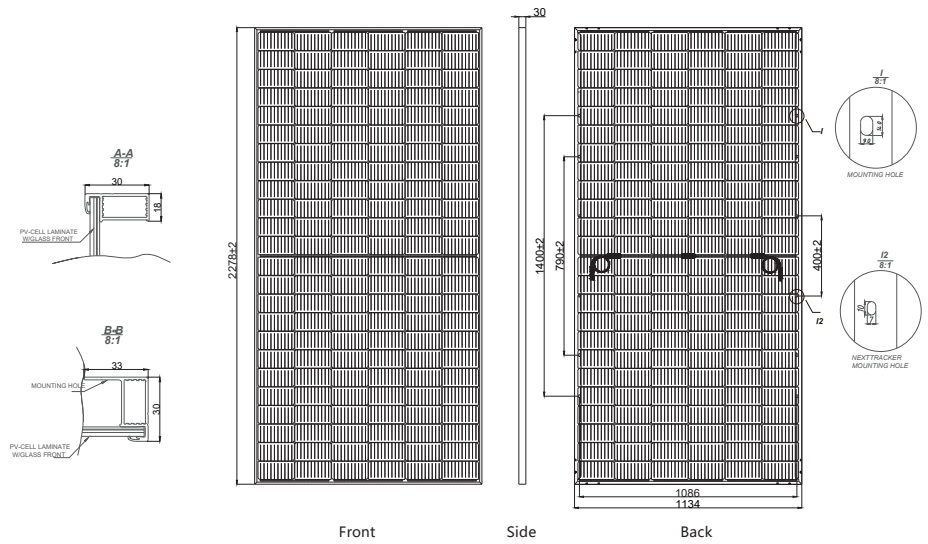
32 kg

Dimensions

2278*1134*30mm

Packaging

36pcs/pallet, 720pcs/ 40'HQ Container



OPERATING CONDITIONS		MECHANICAL CHARACTERISTICS	
Operating Temperature	-40°C~+85°C	Cell Type	N type Monocrystalline 182*91mm
Maximum System Voltage	1500V/DC(IEC)	No. Of Cells	144 pcs in series (6x24)
Maximum Series Fuse Rating	30A	Front Glass	2.0mm, Anti-Reflection Coating
Power Tolerance	0~+3%	Back Glass	2.0mm, Heat Strengthened Glass
Temperature Coefficients Of Pmax	-0.30%/°C	Frame	Anodized Aluminium Alloy, silver or black
Temperature Coefficients Of Voc	-0.25%/°C	Junction Box	IP68 ,3Bypass Diodes
Temperature Coefficients Of Isc	0.046%/°C	Output Cables	300mm in legh or Customized Length
Nominal Module Operating Temperature(NMOT)	43±2°C	Connectors	MC4-EVO2
*Under STC :BACKside Output Ration =Pmax(rear)/Pmax(front) 80%±5%		Mechanical Load	5400Pa(Front)/2400Pa(Back)

Module Type	GSD7S72T-565WT	GSD7S72T-570WT	GSD7S72T-575WT	GSD7S72T-580WT	GSD7S72T-585WT	GSD7S72T-590WT	GSD7S72T-595WT
Maximum Power(Pmax)	565	570	575	580	585	590	595
Maximum Power Voltage (Vmp)	41.92	42.07	42.22	42.37	42.52	42.67	42.82
Maximum Power Current (Imp)	13.48	13.55	13.62	13.69	13.76	13.83	13.90
Open-Circuit Voltage (Voc)	50.60	50.74	50.88	51.02	51.16	51.30	51.44
Short-Circuit Current (Isc)	14.23	14.31	14.39	14.47	14.55	14.63	14.71
Module Efficiency STC (%)	21.87%	22.07%	22.26%	22.45%	22.65%	22.84%	23.03%
STC: Irradiance 1000W/m², AM=1.5, Cell temperature 25°C.							

Module Type	GSD7S72T-565WT	GSD7S72T-570WT	GSD7S72T-575WT	GSD7S72T-580WT	GSD7S72T-585WT	GSD7S72T-590WT	GSD7S72T-595WT
Maximum Power(Pmax)	625	630	635	640	645	650	655
Maximum Power Voltage (Vmp)	41.92	42.06	42.31	42.36	42.52	42.66	42.82
Maximum Power Current (Imp)	14.91	14.98	15.01	15.11	15.17	15.24	15.37
Open-Circuit Voltage (Voc)	50.60	50.74	50.88	51.02	51.16	51.30	51.44
Short-Circuit Current (Isc)	15.76	15.81	15.93	16.02	16.11	16.20	16.29
Module Efficiency BSTC (%)	24.19%	24.39%	24.58%	24.77%	24.97%	25.16%	25.36%

**BSTC: Front side irradiation 1000W/m², Back side reflection irradiation 135W/m², AM=1.5, Cell temperature 25°C.

IV-CURVE

